19-3425: Rev 0: 10/04 EVALUATION KIT **AVAILABLE**

Single-Chip Global Positioning System **Receiver Front-End**

General Description

The MAX2745 complete single-chip global positioning system (GPS) RF front-end downconverter utilizes many innovative and leading-edge RF CMOS design techniques. This high-performance, state-of-the-art device consumes extremely low power and eliminates the need for costly SAW and bulky discrete IF filters. The MAX2745 incorporates a fully integrated low-noise amplifier (LNA) and mixer, IF section, digital sampler, and local oscillator synthesizer. The MAX2745 also provides a voltage supply for an external LNA. In addition, the MAX2745 features a voltage booster, which can extend the power-supply voltage to as low as 1.6V.

The MAX2745 supports both 3rd overtone crystal designs in 32MHz and fundamental frequency crystal designs in 16MHz, as well as a TCXO implementation. In addition, the MAX2745 incorporates an on-chip temperature sensor and crystal oscillator with trimmed capacitors, resulting in a very accurate frequency and additional system cost savings.

The MAX2745 is available in a space-saving 48-pin TQFP package and is specified for the extended (-40°C to +85°C) temperature range. The power consumption of this device is as low as 41mW at 2.4V.

Applications

In-Vehicle Navigation Systems (IVNSs)

Location-Based Services (PDAs and Accessories)

Telematics (Vehicle/Asset Tracking and Inventory Management)

Recreational Handheld/Walkie Talkies

Geographical Information Systems (GISs)

Emergency Roadside Assistance

Emergency Response Systems

Digital Cameras/Camcorders

Consumer Electronics

Features

- ♦ Complete Single-Chip GPS Radio for 16.368MHz and 32.736MHz Floorplans
- ♦ Single-Ended or Differential Outputs at 4.092MHz
- **♦ Low 3.5dB Typical Noise Figure**
- ♦ No External IF SAW or Discrete Filters Required
- **♦** On-Chip Temperature Sensor
- ♦ 2.4V to 3.6V Operational Supply Voltage Range
- ♦ Power Consumption as Low as 41mW at 2.4V
- ♦ Wide -40°C to +85°C Operational Temperature Range

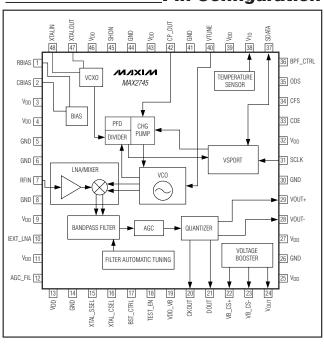
Ordering Information

PART	TEMP RANGE	PIN-PACKAGE		
MAX2745ECM	-40°C to +85°C	48 TQFP-EP*		

^{*}EP = Exposed paddle.

Typical Operating Circuit appears at end of data sheet

Block Diagram/ Pin Configuration



MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

V _{DD} to GND	0.3V to +3.7V
Other Pins to GND	0.3V to $(V_{DD} + 0.3V)$
RF LNA Input Power	+10dBm
Continuous Power Dissipation (TA = +	
48-Pin TQFP-EP (derate 12.5mW/°C	above +70°C)1W
Operating Temperature Range	40°C to +85°C

Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Soldering Temperature (10s)	



Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

(MAX2745 EV kit, V_{DD} = +2.4V to +3.6V, SHDN = GND, T_A = -40°C to +85°C. Typical values are at V_{DD} = +3.0V and T_A = +25°C, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage		2.4		3.6	V
Cupply Current	$V_{DD} = +3.0V, T_A = +25^{\circ}C \text{ (Note 1)}$		20.5	27	mA
Supply Current	Shutdown mode		11		μΑ
Optional External LNA Supply Current	$V_{DD} = +3.0V$			10	mA
Logic-Input High Voltage		2.0			V
Logic-Input Low Voltage				0.5	V
Logic-Input Bias Current		-10		+10	μΑ

AC ELECTRICAL CHARACTERISTICS

(MAX2745 EV kit, V_{DD} = +2.4V to +3.6V, SHDN = GND, T_A = -40°C to +85°C. Typical values are at V_{DD} = +3.0V and T_A = +25°C, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
GENERAL PERFORMANCE						
Maximum Conversion Gain	(Notes 2, 3)		105	120	dB	
Input Frequency			1575.42		MHz	
Noise Figure	Measured at quantizer output		3.5		dB	
Return Loss (S11)			-14		dB	
LNA/Mixer Input IP3	$f_1 = 5.09MHz$ and $f_2 = 7.09MHz$ above carrier frequency		-25		dBm	
Output IF Frequency			4.092		MHz	
OUTPUT STAGE						
Output Rico/Foll Time	Differential (VOUT+, VOUT-), C _L < 20pF		16		no	
Output Rise/Fall Time	Single ended (DOUT), C _L <20pF		6		ns	
Output Valtage Level Lev	Differential		V _{DD} - 0.9		v	
Output-Voltage-Level Low	Single ended		0			
Output-Voltage-Level High	Differential	- V _{DD}		V		
Output-voitage-Level High	Single ended			_ v		

AC ELECTRICAL CHARACTERISTICS (continued)

(MAX2745 EV kit, V_{DD} = +2.4V to +3.6V, SHDN = GND, T_A = -40°C to +85°C. Typical values are at V_{DD} = +3.0V and T_A = +25°C unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
SYNTHESIZER						
Crystal Input Fraguency	Fundamental frequency crystal		16.368		MHz	
Crystal Input Frequency	3rd overtone crystal		32.736			
Charge-Pump Current			0.4		mA	
	foffset = 10kHz offset,		-81			
Phase Noise	$BW_{LOOP} = 70kHz$		-01		dBc/Hz	
Fliase Noise	foffset = 1MHz offset,		-104		UBC/HZ	
	BW _{LOOP} = 70kHz		-104			
Maximum PLL Spur	BW _{LOOP} = 70kHz		-39		dBc	
VCO Tuning Frequency Range	(Notes 2, 3)	150	210	270	MHz	
VCO Tuning Gain	(Notes 2, 3)	150	210	310	MHz/V	
IF STAGE						
IF Stage Gain	VGA set at maximum gain		80		dB	
Dynamic Range IF Stage Gain			56		dB	
Bandpass Filter 1dB Corner	Low-frequency corner		3.1		MHz	
Frequency	High-frequency corner		5.1		IVIITIZ	
Bandpass Filter 3dB Bandwidth			2.0		MHz	
Bandpass Filter 60dB High-Side			6.6		MHz	
Rejection			0.0		IVIITIZ	
Bandpass Filter 60dB Low-Side			1.6		MHz	
Rejection			1.0		IVII IZ	
Image Rejection			17		dB	
In-Band Ripple			1		dB	
AGC Loop Lock Time			1		ms	

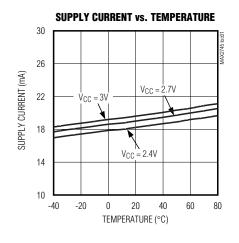
Note 1: At $T_A = +25$ °C, min/max limits are guaranteed by production test.

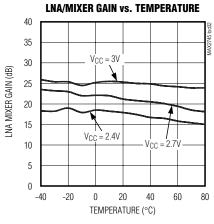
Note 2: At $T_A = -40$ °C, min/max limits are guaranteed by design and characterization.

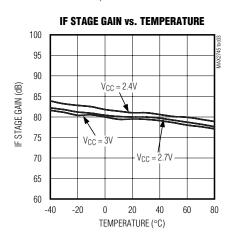
Note 3: At $T_A = +25$ °C and +85°C, min/max limits are guaranteed by production test.

Typical Operating Characteristics

(MAX2745 EV kit, V_{DD} = +3.0V, SHDN = GND, f_{RF} = 1575.42MHz, and T_A = +25°C, unless otherwise noted.)

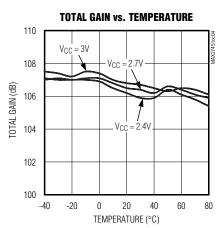


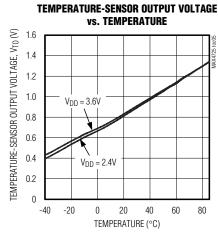


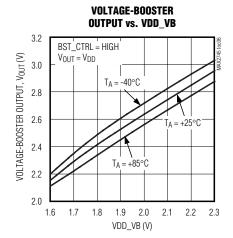


Typical Operating Characteristics (continued)

(MAX2745 EV kit, V_{DD} = +3.0V, SHDN = GND, f_{RF} = 1575.42MHz, and T_A = +25°C, unless otherwise noted.)







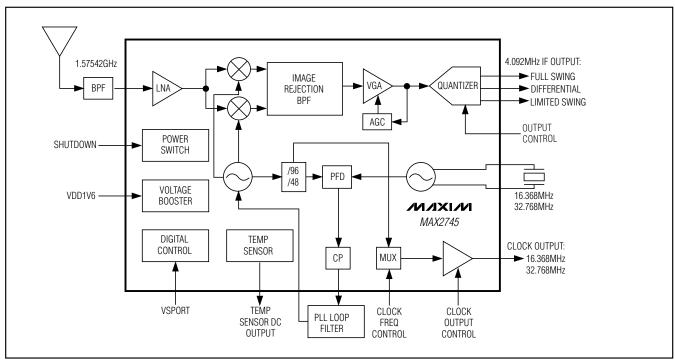
Pin Description

PIN	NAME	FUNCTION	
1	RBIAS	External BIAS Resistor. For normal bias, connect a 100kΩ (1%) resistor to ground.	
2	CBIAS	BIAS Bypass Capacitor. Connect a 0.1µF capacitor to ground.	
3, 4, 9, 11, 13, 25, 27, 32, 39, 43, 46	V _{DD}	Power-Supply Voltage. Bypass with a 0.1µF capacitor to ground as close to the pins as possible.	
5, 6, 8, 14, 26, 30, 41, 44	GND	Ground	
7	RFIN	RF Input Signal. Requires external matching network.	
10	IEXT_LNA	External LNA Voltage Supply	
12	AGC_FIL	AGC External Filter. Requires external RC lowpass filter.	
15	XTAL_SSEL	Crystal Swing Select. Drive logic high for full swing. Drive logic low for limited swing.	
16	XTAL_CSEL	Crystal Clock Select. Drive logic high for fundamental mode of 16.368MHz. Drive logic low for third overtone mode of 32.736MHz.	
17	BST_CTRL	Active-High Boost Control Input. Drive logic high to activate the voltage booster (crystal oscillator is biased from BIAS). Drive logic low to deactivate the voltage booster (crystal oscillator is self-biased).	
18	TEST_EN	Connect to Ground for Normal Operation	
19	VDD_VB	Power Supply for Voltage Booster. Connect to VDD if voltage booster is not used.	
20	CKOUT	Full-Swing Clock Output	
21	DOUT	Single-Ended Full-Swing Digital Output	
22	VB_CS+	Positive Voltage Booster External Floating CAP. Connect a 6nF capacitor to GND.	
23	VB_CS-	Negative Voltage Booster External Floating CAP. Connect a 6nF capacitor to GND.	
24	Vout	Voltage Booster Output. Bypass to GND with a 1µF capacitor as close to the pin as possible.	

Pin Description (continued)

PIN	NAME	FUNCTION
28	VOUT-	Quantizer Analog Negative Limited-Swing Output
29	VOUT+	Quantizer Analog Positive Limited-Swing Output
31	SCLK	Serial Port Clock Input (Bidirectional PAD)
33	COE	Clock Output Enable. Drive logic high to enable the clock output. Drive logic low to disable the clock output.
34	CFS	Clock Frequency Select. Drive logic high to select 16MHz. Drive logic low to select 32MHz.
35	ODS	Output Data Select. Drive logic high to select full-swing output. Drive logic low to select limited-swing output.
36	BPF_CTRL	Bandpass Filter (BPF) Control. Drive logic high to activate the tuning block control BPF. Drive logic low to let BPF be controlled by fuses.
37	SDATA	Serial Port Data (Bidirectional PAD)
38	TEMPOUT	Temperature Sense DC Voltage Output
40	VTUNE	VCO Tuning Input
42	CP_OUT	PLL Charge-Pump Output. Analog high-impedance output. Current source. Connect directly to the PLL loop filter input.
45	SHDN	Active-High Shutdown Input. Drive logic low to disable all device functions. Drive logic high for normal operation.
47	XTALOUT	Crystal Output. Connect directly to the external crystal.
48	XTALIN	Crystal Input. Connect directly to the external crystal or TCXO.

Functional Diagram



Detailed Description

The MAX2745 complete single-chip GPS front-end downconverter utilizes many innovative and leading-edge RF CMOS design techniques. This high-performance, state-of-the-art device consumes extremely low power and eliminates the need for costly SAW and bulky discrete IF filters. The MAX2745 incorporates a fully integrated LNA/mixer, IF section, digital sampler, and local oscillator synthesizer. The MAX2745 also provides voltage supply for an external LNA. In addition, the MAX2745 features a voltage booster that can extend the power-supply voltage to as low as 1.6V.

The MAX2745 supports both 3rd overtone crystal designs in 32MHz and fundamental frequency crystal design in 16MHz, as well as a TCXO implementation. In addition, the MAX2745 incorporates an on-chip temperature sensor and crystal oscillator with trimmed capacitors, resulting in a very accurate frequency and additional system cost savings.

The MAX2745 also incorporates a 2MHz bandwidth bandpass filter to reduce off-band noise. The bandwidth and the center frequency of the bandpass filter are guaranteed by an advanced tuning scheme.

The MAX2745 is offered in a space-saving 48-pin TQFP package. The operational temperature range is specified from -40°C to +85°C. The power consumption of this device is as low as 41mW at 2.4V.

LNA/Mixer

The RF input signal from the GPS antenna is fed through an LNA with a gain of 20dB. The amplified signal is then fed to a mixer that downconverts the signal (1575.42MHz) to a quadrature differential IF of 4.092MHz.

IF Stage

The quadrature IF signals pass through the IF filter, which rejects the out-of-band spurs by more than 60dB and the image noise by 17dB (typ). After the image reject filter, the signal is converted from quadrature to differential. The filtered IF signal is then amplified by the AGC block, which sets the VGA output signal level to a predetermined value through the application using 56dB of dynamic range.

IF Output Selection

The sampled outputs of the GPS signal are available in a single-ended or limited-differential format. The ODS pin controls the output format.

Synthesizer

An on-chip VCO provides quadrature differential LO signals to the downconverting mixer. An on-chip crystal

oscillator driver generates the reference frequency. The integrated synthesizer includes the VCO, crystal oscillator driver, main frequency divider, phase-frequency detector, and charge pump. It uses an off-chip PLL loop filter and crystal. If a TCXO is used, connect the output of the TCXO to XTALIN.

The main division ratio for the synthesizer is 96 or 48. With this division ratio, a low-side injection LO can be used with a 16.368MHz or 32.736MHz crystal. Note that if a 3rd overtone crystal is used for the 32.736MHz, an off-chip notch filter to reject the fundamental frequency is required. The notch filter can be built with one inductor and one capacitor.

Control Block

This block is used mainly for testing purposes and to set the internal trimmed capacitor. This block is programmed through the VSport.

VSport Serial Data Interface

The serial interface within the MAX2745 is used by the baseband to communicate control signals and is also used for internal testing of the device. (This serial port is described in a separate document, which is available upon request.)

Trimmed VCXO Frequency

An on-chip, trimmed capacitor with a temperature coefficient of better than 30ppm/°C is used to compensate for the component variation of the reference frequency associated circuitry. The value of the capacitor is programmed in 512 binary steps and ranges from a minimum of 80fF to a maximum of 40pF, ±20%. Programming is accomplished with the VSport serial interface. The no load capacitance on the crystal out follows the equation:

 $C(\text{no load}) = ([\text{Register Value}] \times 40/512) \text{ pF}$

Upon power-up, the capacitor value is set to the minimum value. This enables the MAX2745 to work with an off-chip, trimmed capacitor. If the baseband has the capability of programming the radio, the off-chip, trimmed capacitor can be omitted by setting the internal trimmed capacitor through the VSPORT.

Temperature Sensor

The MAX2745 features an on-chip temperature sensor to facilitate system temperature compensations in conjunction with the trimmed capacitor. This circuit generates an output voltage at TEMPOUT, which is used to approximate the temperature by the following equation:

$$T = T_O + (V_{OUT} - V_{OUT,TO})/SG$$

where SG is the sensor gain, To is factory-trimmed temperature, which can be any value (normally +27°C), and VouT is the temperature output voltage at To. The coefficient SG in the above equation is targeted to be between 6mV/°C and 8mV/°C, depending on the temperature.

Voltage Booster

The MAX2745 integrates an internal voltage booster to allow proper operation with supply voltages as low as 1.6V. The circuit includes two 6nF floating external capacitors connected to VB_CS± (pins 22 and 23) and a 1 μ F capacitance to VOUT (boosted voltage output, pin 24). To reduce the output voltage ripple, use an external LC lowpass filter, which can be built with two inductors and one capacitor.

Applications Information

Operation with Voltage Booster

Under normal operating conditions, the recommended power-supply voltage ranges from 2.4V to 3.6V. But with the integrated voltage booster on-chip, the MAX2745 can be powered from power-supply voltages as low as 1.6V, and only requires a minimal number of external components. This is not the most efficient operating mode, since the power efficiency will be lowered to less than 50%.

As described in the *Detailed Description* section, to use the voltage booster, connect 6nF floating capacitors to

VB_CS±, pins 22 and 23, and 1µF bypass capacitor to VOUT, pin 24. Connect VOUT (pin 24) to all the power-supply (VDD) pins and pull BST_CTRL, pin 17, high to activate the booster. Then the MAX2745 can be powered from supply voltages ranging from 1.6V to 2.3V at VDD_VB, pin 19, and the voltage booster output can source up to 25mA current. It is recommended that the voltage booster be used as a backup supply. To do this, additional circuits including a voltage monitor and a switch are needed. These components are inexpensive and can be found in the Maxim product family.

Layout Issues

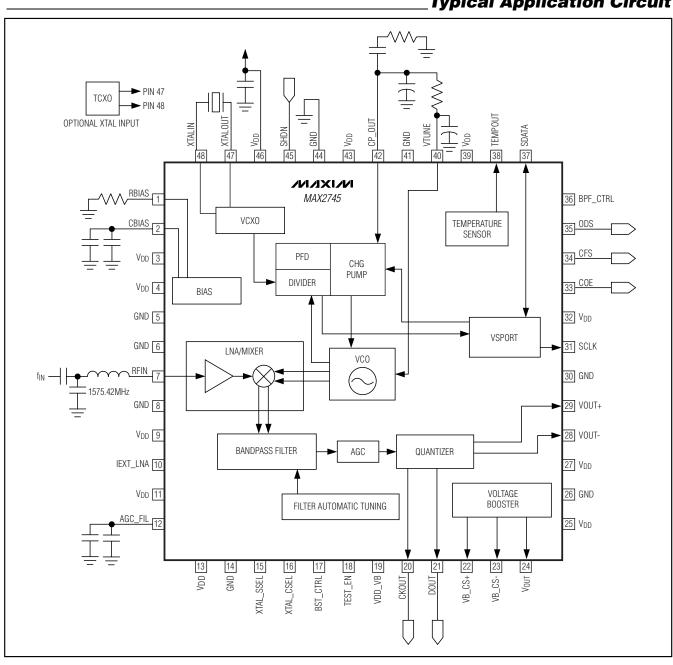
A properly designed PC board is an essential part of any RF/microwave circuit. Use the MAX2745 EV kit as a guide. Use controlled-impedance lines on all frequency inputs and outputs. Use low inductance connections to ground on all ground pins and wherever the components are connected to ground. Place decoupling capacitors close to all VCC connections. For proper operation, connect the metal exposed paddle at the back of the IC to the PC board ground plane with multiple vias.

Chip Information

TRANSISTOR COUNT: 9205

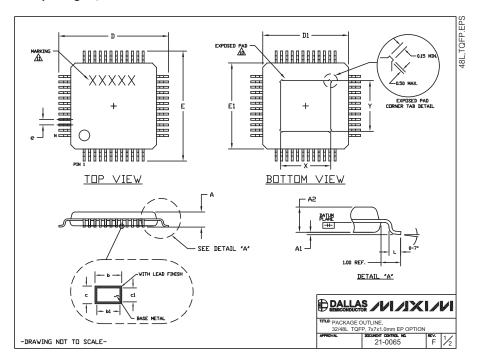
PROCESS: CMOS

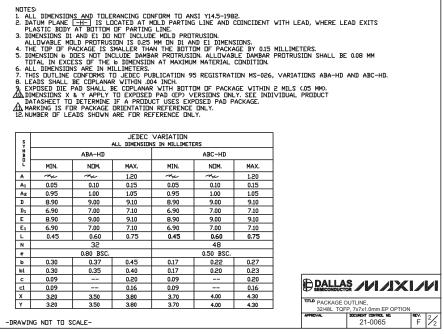
Typical Application Circuit



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)





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